

AMENDMENTS TO THE CLAIMS

1. (Currently Amended) A high-frequency amplifier connectable to a non-reciprocal circuit element having an input impedance lower than an output impedance, comprising:
 - a substrate;
 - an amplifier element provided on said substrate for receiving and amplifying an input signal;
 - a harmonic processing circuit provided on said substrate for providing a proper output load matching of harmonics included in an output signal from said amplifier element to improve an efficiency of said amplifier element; and
 - a filter element provided on said substrate to receive an output from said harmonic processing circuit for selectively passing a signal to be supplied to said non-reciprocal circuit element by using a predetermined frequency as a cutoff frequency.
2. (Original) The high-frequency amplifier according to claim 1, wherein said filter element includes:
 - an inductor arranged on a signal line extending from an output of said harmonic processing circuit to said non-reciprocal circuit element;
 - a first capacitor arranged on said signal line and between a first node on an input side of said inductor and ground; and
 - a second capacitor arranged on said signal line and between a second node on an output side of said inductor and said ground.

3. (Original) The high-frequency amplifier according to claim 1, wherein
the output impedance of said non-reciprocal circuit element is substantially 50 ohm,
and
an output impedance of said high-frequency amplifier and the input impedance of
said non-reciprocal circuit element are substantially in the range of 3 ohm to 30 ohm.
4. (Original) The high-frequency amplifier according to claim 1, wherein
first and second via holes are formed in said substrate for connection of a front side
of said substrate with a ground electrode provided on a rear side of said substrate,
said high-frequency amplifier further comprises said ground electrode, and
said filter element includes:
a first signal line provided on said substrate to extend from an output of said
harmonic processing circuit to said non-reciprocal circuit element;
an inductor arranged on said first signal line;
a second signal line provided on said first signal line to extend from a first node on
an input side of said inductor to said ground electrode via said first via hole;
a first capacitor provided in said second signal line on said substrate;
a third signal line provided on said first signal line to extend from a second node on
an output side of said inductor to said ground electrode via said second via hole; and
a second capacitor provided in said third signal line on said substrate.
5. (Original) The high-frequency amplifier according to claim 1, wherein

said amplifier element amplifies a fundamental frequency represented by f_0 and said predetermined frequency represented by f_c satisfies a relation of $f_0 < f_c < 2f_0$.

6. (Withdrawn) A radio transmission device for supplying a high-frequency signal, comprising:

an amplifier element for receiving and amplifying an input signal;

a substrate having said amplifier element arranged thereon;

a harmonic processing circuit provided on said substrate for matching of harmonics included in an output signal from said amplifier element;

a filter element having at least its part provided on said substrate to receive an output from said harmonic processing circuit for selectively passing the output by using a predetermined frequency as a cutoff frequency;

a first transmission line for transmitting the output from said filter element; and

a non-reciprocal circuit element receiving a signal from said transmission line for non-reciprocally transmitting the signal in the direction in which the signal is transmitted from said transmission line, said non-reciprocal circuit element having an input impedance lower than an output impedance.

7. (Withdrawn) The radio transmission device according to claim 6, wherein

said filter element includes:

an inductor provided on said substrate and arranged on a signal line extending from an output of said harmonic processing circuit to said first transmission line;

a first capacitor provided on said substrate and arranged on said signal line and

between a first node on an input side of said inductor and ground; and

a second capacitor provided on said substrate and arranged on said signal line and between a second node on an output side of said inductor and said ground.

8. (Withdrawn) The radio transmission device according to claim 6, wherein said filter element includes:

a first capacitor provided on said substrate and arranged between ground and a first node on a signal line extending from an output of said harmonic processing circuit to said first transmission line;

an inductor provided outside said substrate and arranged on said signal line at a part of said signal line extending from said first node to said first transmission line; and

a second capacitor provided outside said substrate and arranged on said signal line and between a second node on an output side of said inductor and said ground.

9. (Withdrawn) The radio transmission device according to claim 6, wherein said filter element includes:

a first capacitor provided on said substrate and arranged between ground and a first node on a signal line extending from an output of said harmonic processing circuit to said first transmission line;

a second transmission line provided outside said substrate and arranged on said signal line at a part of said signal line extending from said first node to said first transmission line; and

a second capacitor provided outside said substrate and arranged on said signal line and between a second node on an output side of said second transmission line and said ground.

10. (Withdrawn) The radio transmission device according to claim 6, wherein the output impedance of said non-reciprocal circuit element is substantially 50 ohm, and the input impedance of said non-reciprocal circuit element is substantially in the range of 3 ohm to 30 ohm.

11. (Withdrawn) The radio transmission device according to claim 6, wherein first and second via holes are formed in said substrate for connection of a front side of said substrate with a ground electrode provided on a rear side of said substrate, said radio transmission device further comprises said ground electrode, and said filter element includes:
- a first signal line provided on said substrate to extend from an output of said harmonic processing circuit to said non-reciprocal circuit element;
 - an inductor arranged on said first signal line;
 - a second signal line provided on said first signal line to extend from a first node on an input side of said inductor to said ground electrode via said first via hole;
 - a first capacitor provided in said second signal line on said substrate;
 - a third signal line provided on said first signal line to extend from a second node on an output side of said inductor to said ground electrode via said second via hole; and

a second capacitor provided in said third signal line on said substrate.

12. (Withdrawn) The radio transmission device according to claim 6, wherein
said amplifier element amplifies a fundamental frequency represented by f_0 and said
predetermined frequency represented by f_c satisfies a relation of $f_0 < f_c < 2f_0$.